

AMENDMENTS

In the Claims:

This listing of claim replaces all prior versions, and listings, of claims in the application:

1. (Original) An electroluminescent display device comprising:
 - a plurality of pixels;
 - a pixel selecting transistor provided for each of the pixels;
 - an electroluminescent element provided for each of the pixels; and
 - a driving transistor provided for each of the pixels to drive a corresponding electroluminescent element according to a display signal supplied through a corresponding pixel selecting transistor, the driving transistor comprising a channel of a P type and a lightly-doped-drain structure.
2. (Original) The electroluminescent display device of claim 1, wherein the driving transistor further comprises a gate electrode, a P-type impurity region and a region of no doped impurities that is disposed between the gate electrode and the P-type impurity region.
3. (Currently Amended) The electroluminescent display device of claim 1, wherein the driving transistor further comprises a high concentration region containing a P-type impurity with a concentration of $1 \times 10^{20}/\text{cc}$ or more and being in contact with an electrode, and a low concentration region containing a P-type impurity with a concentration of $1 \times 10^{18}/\text{cc}$ or less and disposed between the high concentration region and the channel ~~region~~.
4. (Currently Amended) The electroluminescent display device of claim 2, wherein the P-type impurity region comprises a high concentration region containing a P-type impurity with a concentration of $1 \times 10^{20}/\text{cc}$ or more and being in contact with an electrode, and a low concentration region containing a P-type impurity with a concentration of $1 \times 10^{18}/\text{cc}$ or less and disposed between the high concentration region and the channel ~~region~~.
5. (New) The electroluminescent display device of claim 1, further comprising a glass substrate on which the pixels, the pixel selecting transistors, the electroluminescent elements and the driving transistors are disposed.